Nanoepitaxy: Homo- and Heterogeneous Synthesis, Characterization, and Device Integration of Nanomaterials

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Editors

3–4 August 2009
San Diego, California, United States

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Please use the following format to cite material from this book:


ISSN 0277-786X
ISBN 9780819476968

Published by
SPIE
P.O. Box 10, Bellingham, Washington 98227-0010 USA
Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445
SPIE.org

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